

FEATURES

1. This specification shall be applied to photocoupler. Model No. LTV-817 as an option.

2. Applicable Models (Business dealing name)

* Dual-in-line package :

LTV702V-V

* Wide lead spacing package :

LTV702VM-V

* Surface mounting package :

LTV702VS-V

* Tape and reel packaging :

LTV702VSTA1-V

3. The relevant models are the models Approved by VDE according to DIN VDE 0884:1992-06

Approved Model No.: LTV-702V / LTV-702VM / LTV-702VS

VDE approved No.: 094722

(According to the specification DIN VDE 0884:1992-06)

* Operating isolation voltage V_{IORM} : 700V (Peak)

* Transient voltage V_{TR} : 6000V (Peak)

* Pollution : 2 (According to VDE 0110-1 : 1997-04)

* Clearances distance (Between input and output) : 7.0mm (MIN.)

* Creepage distance (Between input and output) : 7.0mm (MIN.)

* Isolation thickness between input and output : 0.4mm (MIN.)

* Safety limit values Current (Isi) : 400mA (Diode side)

Power (Psi) : 700mW (Phototransistor side)

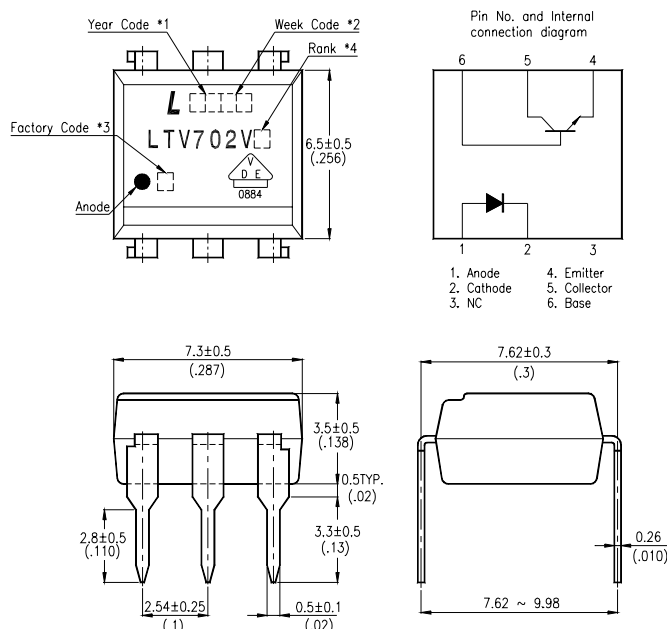
Temperature(Tsi) : 175°C

In order to keep safety electric isolation of photocoupler, please set the protective circuit to keep within safety limit values when the actual application equipment troubled.

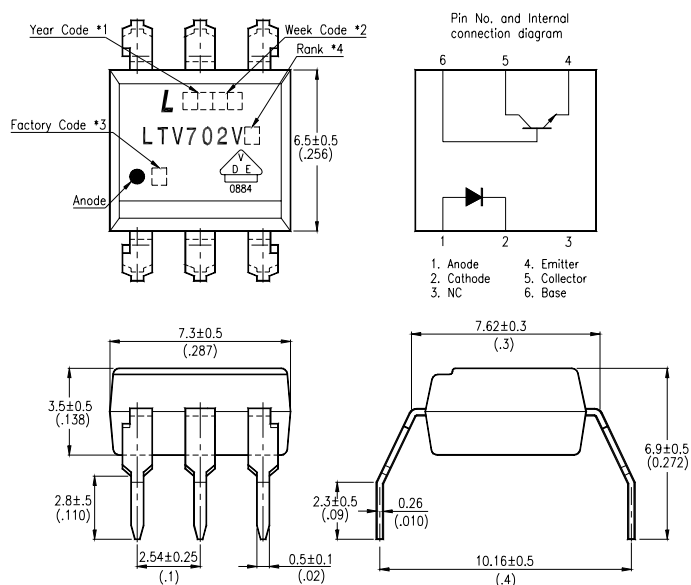
* Indication of VDE 0884 approval prints "  " on sleeve package.

OUTLINE DIMENSIONS

LTV702V-V :



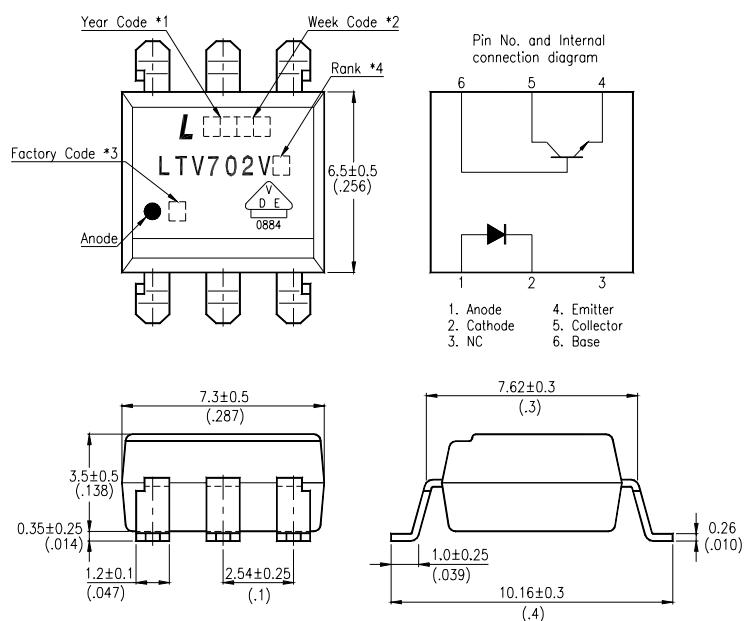
LTV702VM-V :



- *1. Year date code.
- *2. 2-digit work week.
- *3. Factory identification mark shall be marked (Z : Taiwan, Y : Thailand, X : China).
- *4. Rank shall be or shall not be marked.

OUTLINE DIMENSIONS

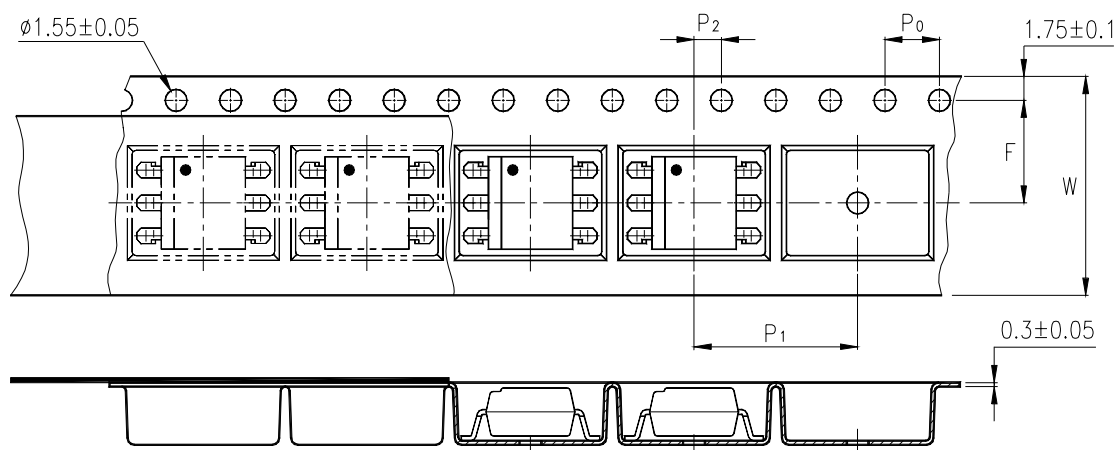
LTV702VS-V :



- *1. Year date code.
- *2. 2-digit work week.
- *3. Factory identification mark shall be marked (Z : Taiwan, Y : Thailand, X : China).
- *4. Rank shall be or shall not be marked.

TAPING DIMENSIONS

LTV702VSTA1-V :



Description	Symbol	Dimensions in mm (inches)
Tape wide	W	16 ± 0.3 (.63)
Pitch of sprocket holes	P_0	4 ± 0.1 (.15)
Distance of compartment	F	7.5 ± 0.1 (.295)
Distance of compartment to compartment	P_1	12 ± 0.1 (.472)

ABSOLUTE MAXIMUM RATING

(Ta = 25°C)

PARAMETER		SYMBOL	RATING	UNIT
INPUT	Forward Current	I _F	60	mA
	Reverse Voltage	V _R	6	V
	Power Dissipation	P	105	mW
OUTPUT	Collector - Emitter Voltage	V _{CEO}	70	V
	Emitter - Collector Voltage	V _{ECO}	6	V
	Collector - Base Voltage	V _{CBO}	70	V
	Emitter - Base Voltage	V _{EBO}	6	V
	Collector Current	I _C	50	mA
	Collector Power Dissipation	P _C	160	mW
Total Power Dissipation		P _{tot}	200	mW
*1 Isolation Voltage		V _{iso}	5,000	V _{Rms}
Operating Temperature		T _{opr}	-55 ~ +100	°C
Storage Temperature		T _{stg}	-55 ~ +150	°C
*2 Soldering Temperature		T _{sol}	260	°C

*1. AC For 1 Minute, R.H. = 40 ~ 60%

Isolation voltage shall be measured using the following method.

- (1) Short between anode and cathode on the primary side and between collector, emitter and base on the secondary side.
- (2) The isolation voltage tester with zero-cross circuit shall be used.
- (3) The waveform of applied voltage shall be a sine wave.

*2. For 10 Seconds

ELECTRICAL - OPTICAL CHARACTERISTICS

(Ta = 25°C)

PARAMETER		SYMBOL	MIN.	TYP.	MAX.	UNIT	CONDITIONS
INPUT	Forward Voltage	V _F	—	1.4	1.7	V	I _F =60mA
	Reverse Current	I _R	—	—	10	μA	V _R =6V
	Terminal Capacitance	C _t	—	30	250	pF	V=0, f=1KHz
OUTPUT	Collector Dark Current	I _{CEO}	—	—	50	nA	V _{CE} =10V, I _F =0
	Collector-Emitter Breakdown Voltage	BV _{CEO}	70	—	—	V	I _C =0.1mA I _F =0
	Emitter-Collector Breakdown Voltage	BV _{ECO}	6	—	—	V	I _E =10μA I _F =0
	Collector-Base Breakdown Voltage	BV _{CBO}	70	—	—	V	I _C =0.1mA I _F =0
TRANSFER CHARACTERISTICS	Collector Current	I _C	4	—	32	mA	I _F =10mA V _{CE} =5V
	* Current Transfer Ratio	CTR	40	—	320	%	
	Collector-Emitter Saturation Voltage	V _{CE(sat)}	—	0.25	0.4	V	I _F =10mA I _C =2.5mA
	Isolation Resistance	R _{iso}	5×10 ¹⁰	1×10 ¹¹	—	Ω	DC500V 40 ~ 60% R.H.
	Floating Capacitance	C _f	—	0.6	1	pF	V=0, f=1MHz
	Cut-Off Frequency	f _c	—	150	—	kHz	V _{CC} =5V, I _F =10mA R _L =75Ω, -3dB
	Response Time (Rise)	t _r	—	2	7	μs	V _{CC} =5V, I _F =10mA R _L =75Ω
	Response Time (Fall)	t _f	—	2	8	μs	

$$* \text{ CTR} = \frac{I_C}{I_F} \times 100\%$$

RANK TABLE OF CURRENT TRANSFER RATIO CTR

MODEL NO.	RANK MARK	CTR (%)
LTV702V-V	A	40 ~ 80
	B	63 ~ 125
	C	100 ~ 200
	D	160 ~ 320
	A or B or C or D or No mark	40 ~ 320

CONDITIONS	$I_F = 10 \text{ mA}$ $V_{CE} = 5 \text{ V}$ $T_a = 25 \text{ }^{\circ}\text{C}$
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ISOLATION SPECIFICATION ACCORDING TO VDE 0884

Parameter		Symbol	Conditions	Rating	Unit	Remark
Class of environmental test		-	DIN IEC68	55/100/21	-	
Pollution		-	DIN VDE0110	2	-	
Maximum Operating Isolation Voltage		V_{IORM}	-	700	V_{PEAK}	
Partial Discharge Test Voltage (Between Input and Output)	Diagram 1	V_{pr}	$tp=60s, qc<5pC$	1050	V_{PEAK}	Refer to the Diagram 1, 2
	Diagram 2		$tp=1s, qc<5pC$	1313	V_{PEAK}	
Maximum Over-voltage		$V_{INITIAL}$	$t_{INI} = 10s$	6000	V_{PEAK}	
Safety Maximum Ratings						Refer to the Figure 1, 3
1) Case Temperature		T_{si}	$I_F = 0, P_c = 0$	175	$^{\circ}C$	
2) Input Current		I_{si}	$P_c=0$	400	mA	
3) Electric Power (Output or Total Power Issipation)		P_{si}	-	700	mW	
Isolation Resistance (Test Voltage Between Input and Output : DC500V)		R_{ISO}	$T_a=T_{si}$	MIN. 10^9	Ω	
			$T_a=T_{opr}(MAX.)$	MIN. 10^{11}		
			$T_a=25^{\circ}C$	MIN. 10^{12}		

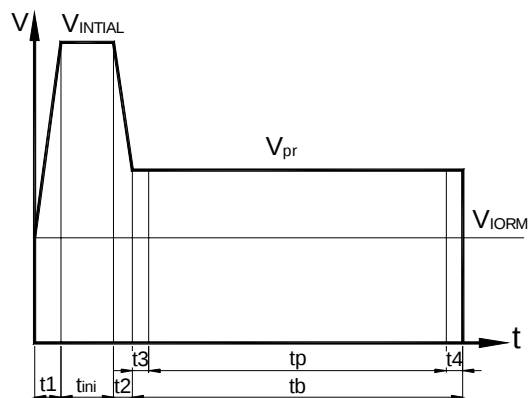
Precautions in performing isolation test

* Partial discharge test methods shall be the ones according to the specifications of VDE 0884:1992-06

* Please don't carry out isolation test (V_{iso}) over $V_{INITIAL}$, This product deteriorates isolation characteristics by partial discharge due to applying high voltage (ex. $V_{INITIAL}$). And there is possibility that this product occurs partial discharge in operating isolation voltage (V_{IORM})

PARTIAL DISCHARGE TEST METHOD

Method (A) for type testing and random testing.



t1, t2

= 1 to 10s

t3, t4

= 1s

t_p (Partial Discharge Measuring Time)

= 60s

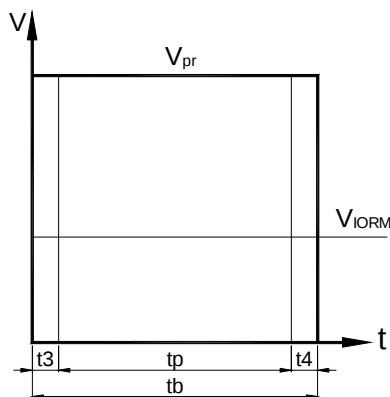
t_b

= 62s

t_{ini}

= 10s

Method (B) for routine testing.



t3, t4

= 0.1s

t_p (Partial Discharge Measuring Time)

= 1s

t_b

= 1.2s

The partial discharge level shall not exceed 5 pC during the partial discharge measuring time interval t_p under the test conditions shown above.

CHARACTERISTICS CURVES

Fig.1 Forward Current vs.
Ambient Temperature

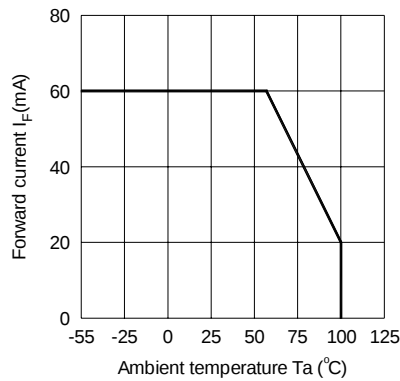


Fig.2 Collector Power Dissipation vs.
Ambient Temperature

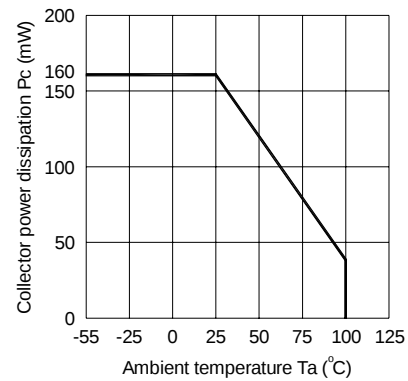


Fig.3 Collector-emitter Saturation
Voltage vs. Forward Current

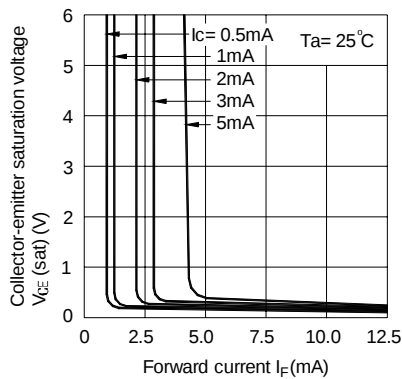


Fig.4 Forward Current vs.
Forward Voltage

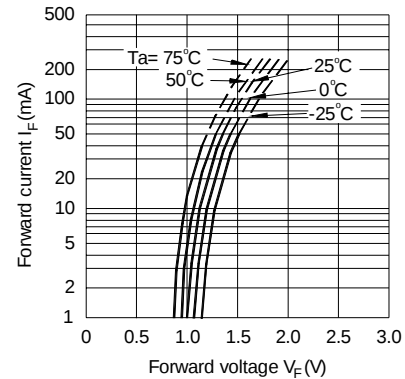


Fig.5 Current Transfer Ratio vs.
Forward Current

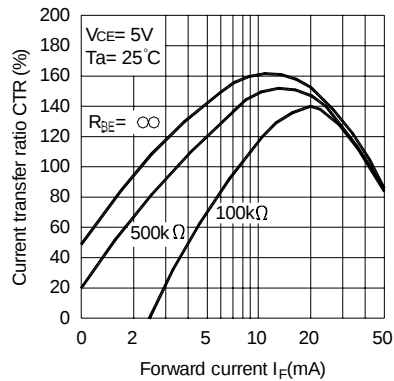
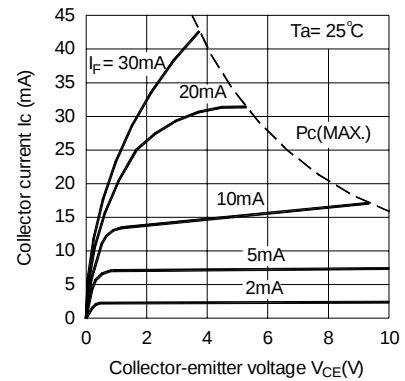


Fig.6 Collector Current vs.
Collector-emitter Voltage



CHARACTERISTICS CURVES

Fig.7 Relative Current Transfer Ratio vs. Ambient Temperature

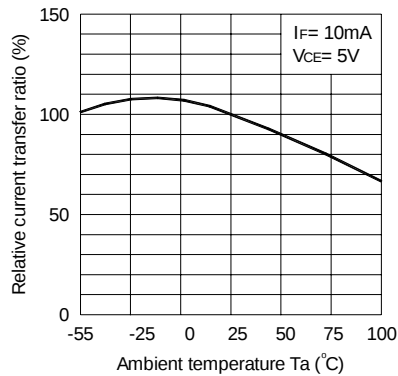


Fig.8 Collector-emitter Saturation Voltage vs. Ambient Temperature

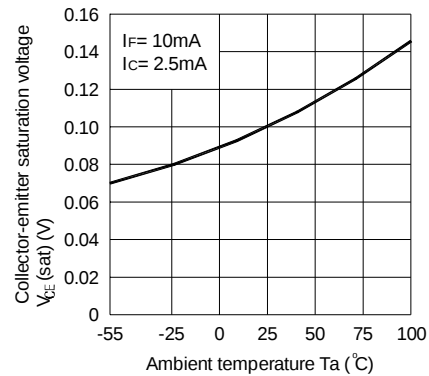


Fig.9 Collector Dark Current vs. Ambient Temperature

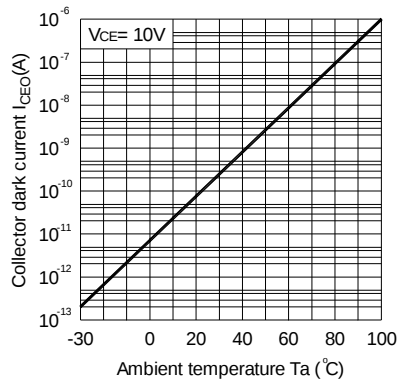


Fig.10 Response Time vs. Load Resistance

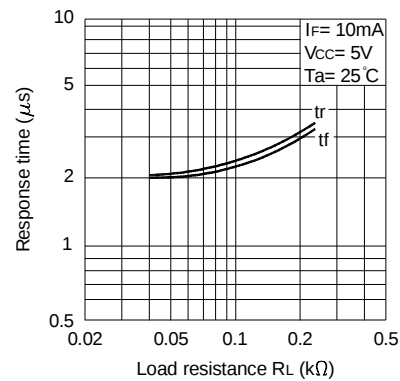
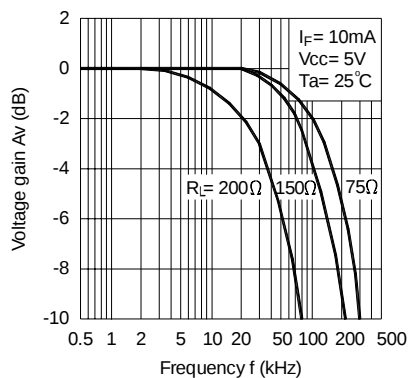
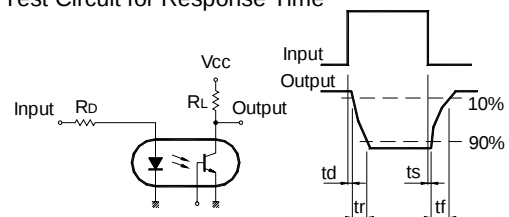


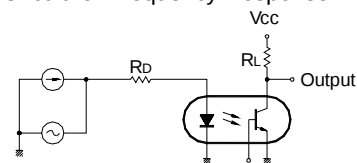
Fig.11 Frequency Response



Test Circuit for Response Time



Test Circuit for Frequency Response



RECOMMENDED FOOT PRINT PATTERNS (MOUNT PAD)

Unit : mm

